

INFORMATION DISCLOSURE CITATION
(Use several sheets if necessary)

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Applicant(s)
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Group Art Unit
Not Yet Assigned

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

U.S. PATENT APPLICATION PUBLICATIONS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
	2003-46128	02/14/2003	JAPAN				ABS
	2000-349336	12/15/2000	JAPAN				ABS

OTHER DOCUMENTS *(Including Author, Title, Date, Pertinent Pages, Etc.)*

Yang, Ying-Ge, "Preparation and Structural Properties for GaN Films Grown on Si (1 1 1) by Annealing", Applied Surface Science, Vol. 193, 2002, pages 254 -260

EXAMINER

/Sarah Salerno/

DATE CONSIDERED

08/01/2008

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